		ATTY DOCKET NO. ITO.0553US (P16341)	SERIAL NO. 10/634,153
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W	A.	5,815,425	09/29/1998	Wong et al.			
W	B.	6,044,004	03/28/2000	Kramer			
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	I.						

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T.S. 9/25/06 W	J.	EP 0 788 257	08/06/~~2997~~ 1997	Europe				
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	T.	
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EXAMINER	DATE CONSIDERED
V. Nguyen	4/3/2005

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.